

## Features

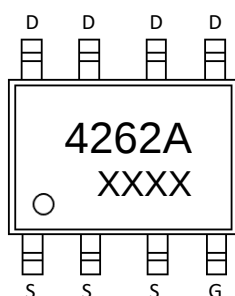
- High density cell design for ultra low  $R_{DS(ON)}$
- Good stability and uniformity with high  $E_{AS}$
- Excellent package for good heat dissipation

## Product Summary

| $V_{DS}$ | $R_{DS(ON)}$ TYP | $I_D$ |
|----------|------------------|-------|
| 60V      | 5.2mΩ@10V        | 16.5A |
|          | 6.6mΩ@4.5V       |       |

## Application

- Power switching application
- Load Switch

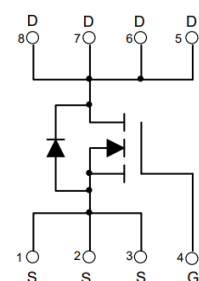


4262A: Device code  
XXXX : Code

Marking and pin assignment



SOP-8 top view



Schematic diagram



Pb-Free



RoHS



Halogen-Free

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol                                          | Parameter                              |         | Rating     | Unit |
|-------------------------------------------------|----------------------------------------|---------|------------|------|
| Common Ratings (TC=25°C Unless Otherwise Noted) |                                        |         |            |      |
| V <sub>DS</sub>                                 | Drain-Source Breakdown Voltage         |         | 60         | V    |
| V <sub>GS</sub>                                 | Gate-Source Voltage                    |         | ±20        | V    |
| T <sub>J</sub>                                  | Maximum Junction Temperature           |         | 150        | °C   |
| T <sub>STG</sub>                                | Storage Temperature Range              |         | -50 to 155 | °C   |
| I <sub>S</sub>                                  | Diode Continuous Forward Current       | Tc=25°C | 16.5       | A    |
| Mounted on Large Heat Sink                      |                                        |         |            |      |
| I <sub>DM</sub>                                 | Pulse Drain Current Tested             | Tc=25°C | 85         | A    |
| I <sub>D</sub>                                  | Continuous Drain Current               | Tc=25°C | 16.5       | A    |
| P <sub>D</sub>                                  | Maximum Power Dissipation              | Tc=25°C | 2.5        | W    |
| R <sub>θJA</sub>                                | Thermal Resistance Junction-to-Ambient |         | 50         | °C/W |

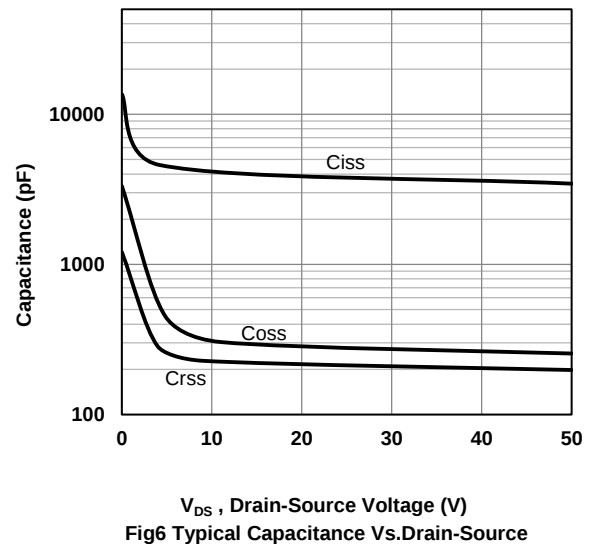
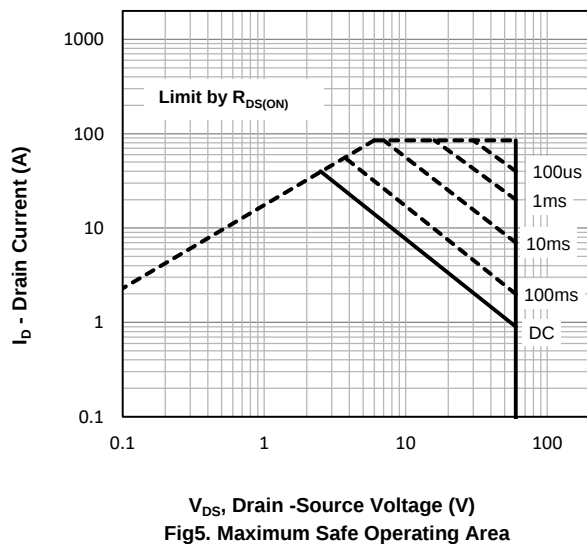
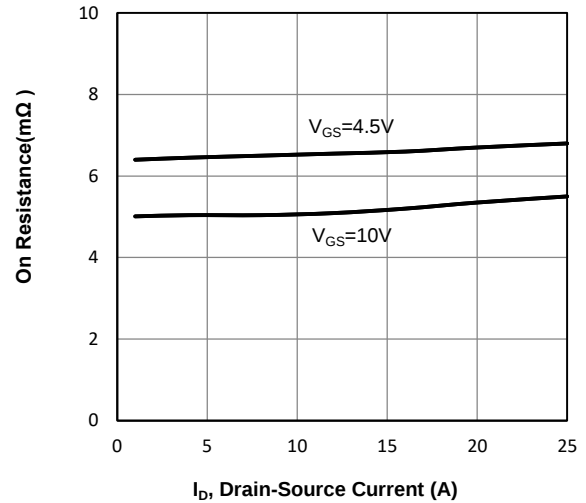
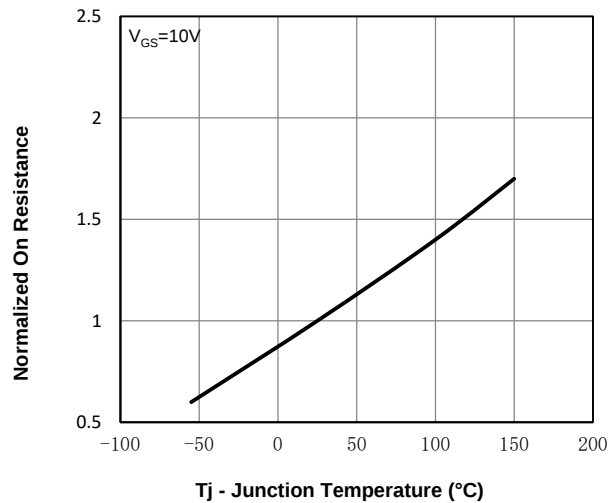
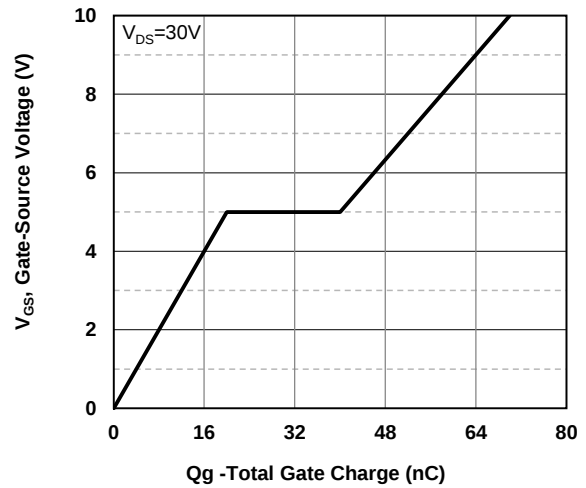
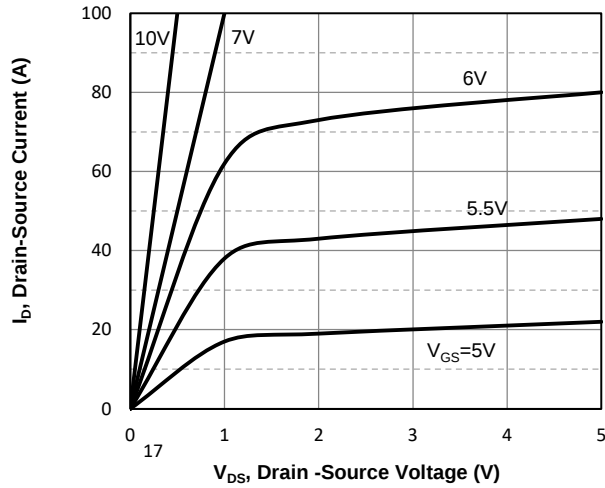
## Ordering Information (Example)

| Type    | Package | Marking | Minimum Package(pcs) | Inner Box Quantity(pcs) | Outer Carton Quantity(pcs) | Delivery Mode |
|---------|---------|---------|----------------------|-------------------------|----------------------------|---------------|
| MQ4262A | SOP-8   | 4262A   | 3,000                | 6,000                   | 42,000                     | 13"reel       |

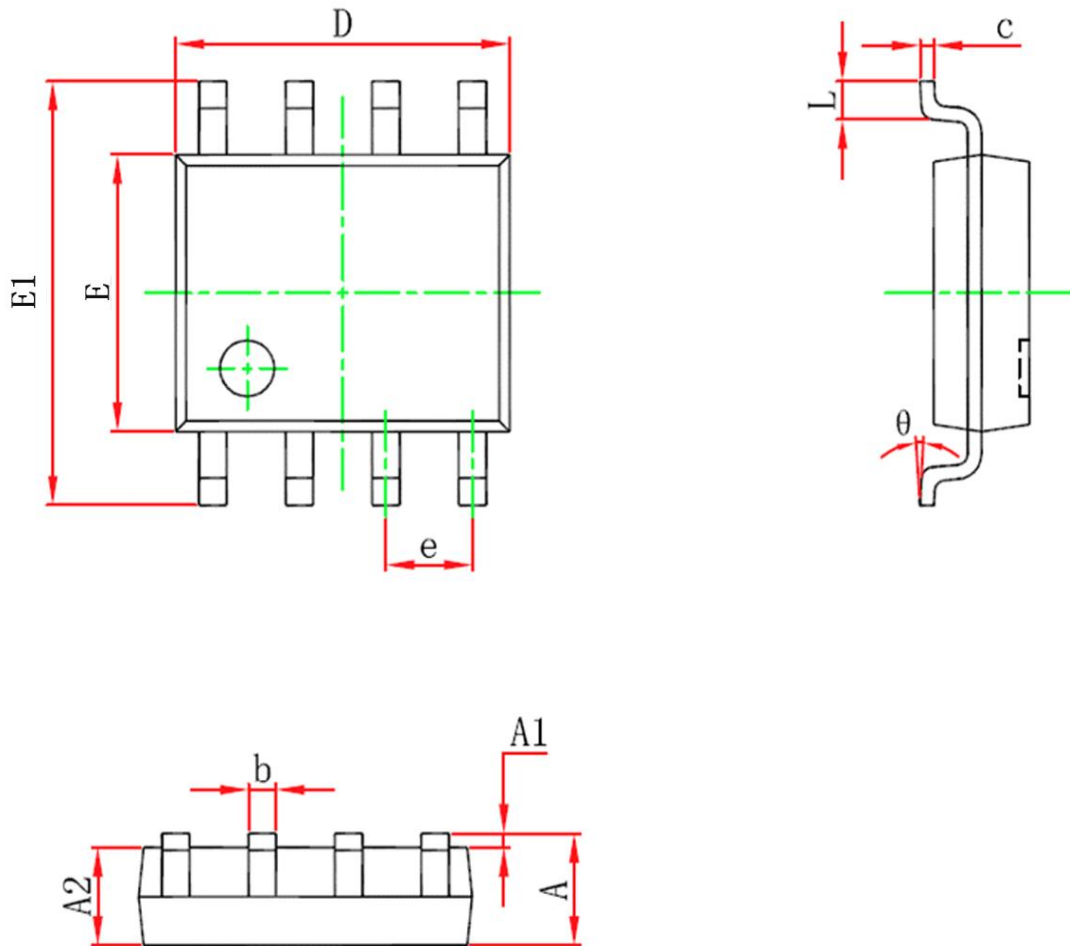
**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

| Symbol                                                                               | Parameter                        | Condition                                                                                | Min | Typ  | Max  | Unit |
|--------------------------------------------------------------------------------------|----------------------------------|------------------------------------------------------------------------------------------|-----|------|------|------|
| Static Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated)  |                                  |                                                                                          |     |      |      |      |
| BV <sub>(BR)DSS</sub>                                                                | Drain-Source Breakdown Voltage   | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA                                               | 60  | --   | --   | V    |
| I <sub>DSS</sub>                                                                     | Zero Gate Voltage Drain Current  | V <sub>DS</sub> =60V, V <sub>GS</sub> =0V                                                | --  | --   | 1.0  | μA   |
| I <sub>GSS</sub>                                                                     | Gate-Body Leakage Current        | V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V                                               | --  | --   | ±100 | nA   |
| V <sub>GS(th)</sub>                                                                  | Gate Threshold Voltage           | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                                 | 1.2 | --   | 2.2  | V    |
| R <sub>DS(on)</sub>                                                                  | Drain-Source On-State Resistance | V <sub>GS</sub> =10V, I <sub>D</sub> =16A                                                | --  | 5.2  | 6.5  | mΩ   |
|                                                                                      |                                  | V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A                                               | --  | 6.6  | 8.5  | mΩ   |
| Dynamic Electrical Characteristics @ T <sub>J</sub> = 25°C (unless otherwise stated) |                                  |                                                                                          |     |      |      |      |
| C <sub>ISS</sub>                                                                     | Input Capacitance                | V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1MHz                                        | --  | 3782 | --   | pF   |
| C <sub>OSS</sub>                                                                     | Output Capacitance               |                                                                                          | --  | 297  | --   | pF   |
| C <sub>RSS</sub>                                                                     | Reverse Transfer Capacitance     |                                                                                          | --  | 218  | --   | pF   |
| Switching Characteristics                                                            |                                  |                                                                                          |     |      |      |      |
| Q <sub>g</sub>                                                                       | Total Gate Charge                | V <sub>DS</sub> =30V, I <sub>D</sub> =20A,<br>V <sub>GS</sub> =10V                       | --  | 77   | --   | nC   |
| Q <sub>gs</sub>                                                                      | Gate Source Charge               |                                                                                          | --  | 21   | --   | nC   |
| Q <sub>gd</sub>                                                                      | Gate Drain Charge                |                                                                                          | --  | 24   | --   | nC   |
| t <sub>d(on)</sub>                                                                   | Turn-on Delay Time               | V <sub>DS</sub> =30V, I <sub>D</sub> =20A,<br>V <sub>GS</sub> =10V, R <sub>G</sub> =1.8Ω | --  | 18   | --   | nS   |
| t <sub>r</sub>                                                                       | Turn-on Rise Time                |                                                                                          | --  | 88   | --   | nS   |
| t <sub>d(off)</sub>                                                                  | Turn-Off Delay Time              |                                                                                          | --  | 37   | --   | nS   |
| t <sub>f</sub>                                                                       | Turn-Off Fall Time               |                                                                                          | --  | 85   | --   | nS   |
| Source- Drain Diode Characteristics                                                  |                                  |                                                                                          |     |      |      |      |
| V <sub>SD</sub>                                                                      | Forward on voltage               | T <sub>J</sub> =25°C, I <sub>S</sub> =10A                                                | --  | --   | 1.2  | V    |

## Typical Operating Characteristics



SOP-8 Package information



| Symbol | Dimensions in Millimeters(mm) |       | Dimensions In Inches |       |
|--------|-------------------------------|-------|----------------------|-------|
|        | Min                           | Max   | Min                  | Max   |
| A      | 1.450                         | 1.750 | 0.057                | 0.068 |
| A1     | 0.100                         | 0.250 | 0.003                | 0.009 |
| A2     | 1.350                         | 1.550 | 0.053                | 0.061 |
| b      | 0.330                         | 0.510 | 0.012                | 0.020 |
| c      | 0.170                         | 0.250 | 0.006                | 0.009 |
| D      | 4.700                         | 5.100 | 0.185                | 0.200 |
| e      | 1.270(BSC)                    |       | 0.050(BSC)           |       |
| E      | 3.800                         | 4.000 | 0.149                | 0.157 |
| E1     | 5.800                         | 6.200 | 0.228                | 0.244 |
| L      | 0.400                         | 1.270 | 0.015                | 0.050 |
| θ      | 0°                            | 8°    | 0°                   | 8°    |